

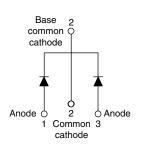
# VS-30CTQ0...PbF Series, VS-30CTQ0...-N3 Series

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# Schottky Rectifier, 2 x 15 A

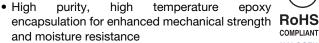




PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 15 A				
$V_R$	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	0.56 V				
I <sub>RM</sub> max.	45 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	13 mJ				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

## **DESCRIPTION**

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	OL CHARACTERISTICS VALUES UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	30	Α					
V <sub>RRM</sub>		50/60	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1000	Α					
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V					
T <sub>J</sub>	Range	- 55 to 150	°C					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS- 30CTQ050PbF	VS- 30CTQ050-N3	VS- 30CTQ060PbF	VS- 30CTQ060-N3	UNITS
Maximum DC reverse voltage	$V_R$	50	50	60	60	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	30	00	00	V

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	per device		50 % duty cycle at T <sub>C</sub> = 105 °C, rectangular waveform		30		
See fig. 5	per leg	I <sub>F(AV)</sub>			15	Α	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1000		
		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	260		
Non-repetitive avalanche ene	n-repetitive avalanche energy per leg $E_{AS}$ $T_{J} = 25$ °C, $I_{AS} = 1.50$ A, L = 11.5 mH		13	mJ			
Repetitive avalanche current per leg I <sub>AR</sub>		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1.50	Α	



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T <sub>.1</sub> = 25 °C	0.62	V		
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.82			
See fig. 1	V FM (1)	15 A	T 405.00	0.56			
		30 A	T <sub>J</sub> = 125 °C	0.71			
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	- V <sub>R</sub> = Rated V <sub>R</sub>	0.80	- mA		
See fig. 2		T <sub>J</sub> = 125 °C		45			
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.39	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		8.47	mΩ		
Maximum junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		720	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 150	°C			
Maximum thermal resistance, junction to case per leg	В	DC eneration	3.25				
Maximum thermal resistance, junction to case per package	- R <sub>thJC</sub>	DC operation	1.63	°C/W			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Mounting torque minimum			6 (5)	kgf · cm			
Mounting torque — maximum			12 (10)	(lbf $\cdot$ in)			
Marking dayion		O		Q050			
Marking device		Case style TO-220AB	30CTQ060				

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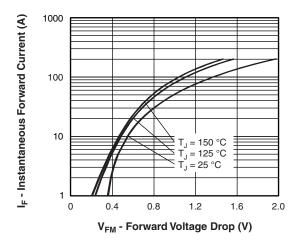


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

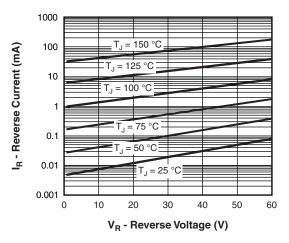


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

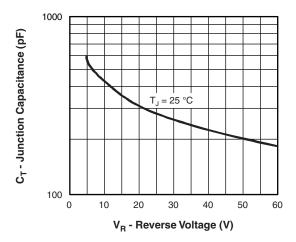


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

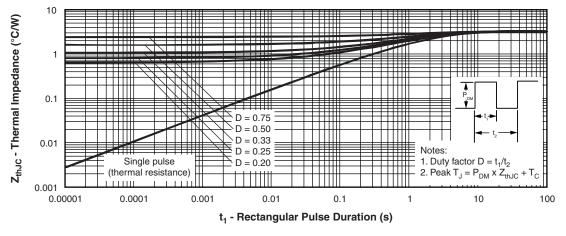


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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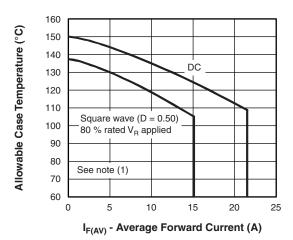


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

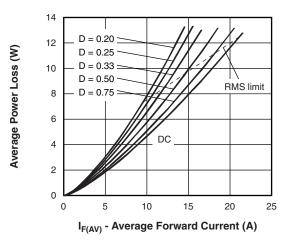


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

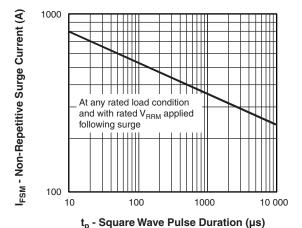


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

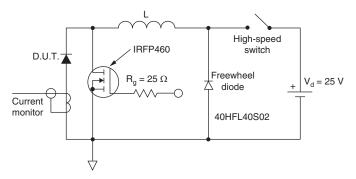


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

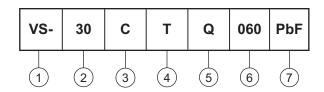
 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = Forward power loss = I_{F(AV)} \times V_{FM} \ at \ (I_{F(AV)}/D) \ (see fig. 6); \\ Pd_{REV} = Inverse power loss = V_{R1} \times I_R \ (1 - D); I_R \ at \ V_{R1} = 10 \ V$ 

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## **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Current rating (30 = 30 A)
- Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

- Voltage ratings — 050 = 50 V 060 = 60 V

7 - Environmental digit

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-30CTQ050PbF	50	1000	Antistatic plastic tube					
VS-30CTQ050-N3	50	1000	Antistatic plastic tube					
VS-30CTQ060PbF	50	1000	Antistatic plastic tube					
VS-30CTQ060-N3	50	1000	Antistatic plastic tube					

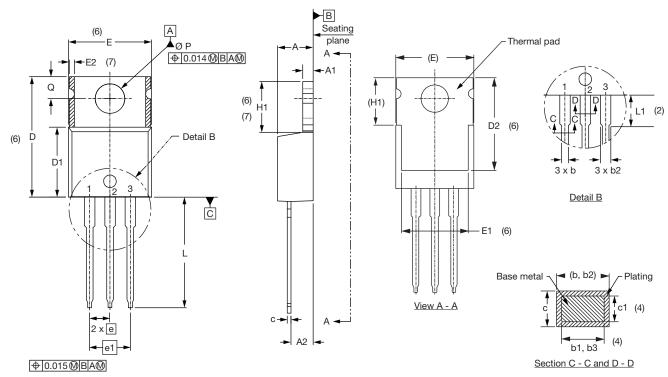
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95222</u>						
Dout moulting information	TO-220ABPbF	www.vishay.com/doc?95225				
Part marking information	TO-220AB-N3	www.vishay.com/doc?95028				



## Vishay Semiconductors

## **TO-220AB**

## **DIMENSIONS** in millimeters and inches



## Lead assignments

## **Diodes**

- 1. Anode/open
- 2. Cathode
- 3. Anode

## Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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